



100V NPN MEDIUM POWER TRANSISTOR IN TO252

Features

- BV_{CEO} > 100V
- I_C = 6A Continuous Collector Current
- I_{CM} = 10A Peak Pulse Current
- Ideal for Power Switching or Amplification Applications
- Complementary PNP Type: MJD42CQ
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- The MJD41CQ is suitable for automotive applications requiring specific change control; this part is AEC-Q101 qualified, PPAP capable, and manufactured in IATF16949 certified facilities.

https://www.diodes.com/quality/product-definitions/

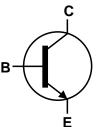
Mechanical Data

- Package: TO252
- Package Material: Molded Plastic, "Green" Molding Compound UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 @3
- Weight: 0.34 grams (Approximate)

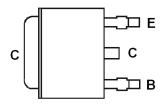




Top View



Device Schematic



Pin Out Configuration Top View

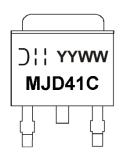
Ordering Information (Note 4)

Part Number	Pookogo	Marking	Reel Size (inches)	Tape Width (mm)	Pac	king
Part Number	Part Number Package		Marking Reel Size (Inches)		Qty.	Carrier
MJD41CQ-13	TO252 (DPAK)	MJD41C	13	16	2500	Reel

Notes:

- 1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.
 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information



MJD41C = Product Type Marking Code ☐ = Manufacturers' Code Marking YYWW = Date Code Marking YY = Last Two Digits of Year (ex: 24 = 2024) WW = Week Code (01 to 53)



Absolute Maximum Ratings ($@T_A = +25^{\circ}C$, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	Vcво	120	V
Collector-Emitter Voltage	V _{CEO}	100	V
Emitter-Base Voltage	VEBO	7	V
Continuous Collector Current	Ic	6	A
Peak Pulse Collector Current	I _{CM}	10	A
Continuous Base Current	lв	2	A

Thermal Characteristics ($@T_A = +25^{\circ}C$, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
	(Note 5)		2.7		
Power Dissipation	(Note 6)	P _D	2.4	W	
	(Note 7)		1.5		
	(Note 5)		46		
Thermal Resistance, Junction to Ambient Air	(Note 6)	$R_{ heta JA}$	52	°C/W	
	(Note 7)		83		
Operating and Storage Temperature Range	TJ, TSTG	-55 to +150	°C		

ESD Ratings (Note 8)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge – Human Body Model	ESD HBM	4000	V	3A
Electrostatic Discharge – Machine Model	ESD MM	400	V	С

Notes:

- 5. For a device mounted with the exposed collector pad on 25mm × 25mm 2oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air conditions whilst operating in a steady state.
- 6. Same as note (5), except mounted on 25mm × 25mm 1oz copper.
- 7. Same as note (5), except mounted on minimum recommended pad (MRP) layout.

 8. Refer to JEDEC specification JESD22-A114 and JESD22-A115.



Thermal Characteristics

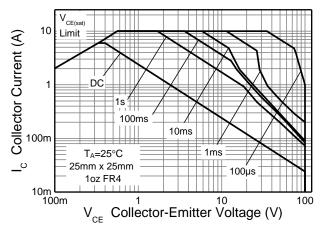


Figure 1. Safe Operating Area

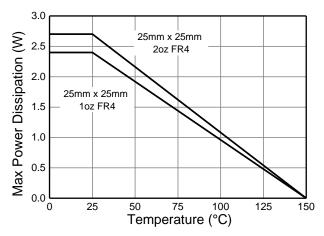


Figure 2. Derating Curve

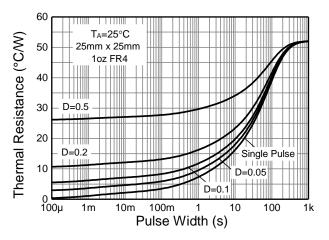


Figure 3. Transient Thermal Impedance

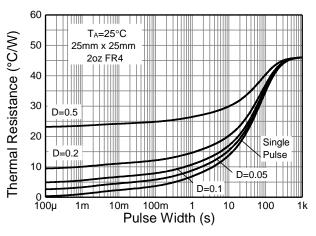


Figure 4. Transient Thermal Impedance

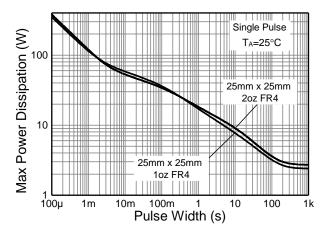


Figure 5. Pulse Power Dissipation



Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

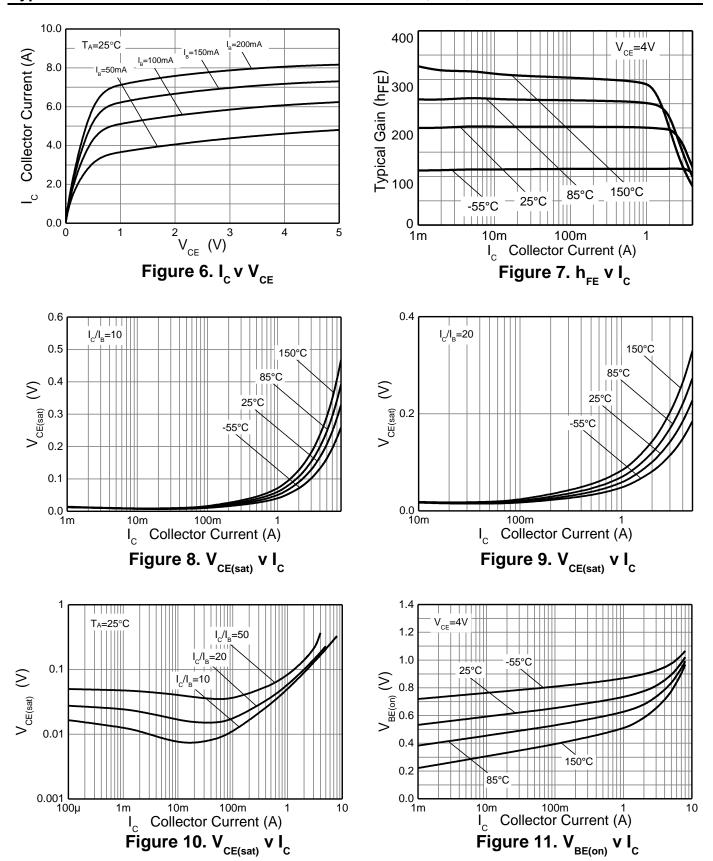
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	ВУсво	120	_	_	V	Ic = 100μA
Collector-Emitter Breakdown Voltage (Note 9)	BV _{CEO}	100	_	_	V	I _C = 10mA
Emitter-Base Breakdown Voltage	BVEBO	7	_	_	V	I _E = 100μA
Collector Cut-Off Current	I _{CES}	_	_	1	μΑ	V _{CE} = 100V
Collector-Base Cut-Off Current	I _{CBO}	_	_	100	nA	V _{CB} = 100V
Emitter Cut-Off Current	I _{EBO}	_	_	1	μΑ	V _{EB} = 6V
Collector-Emitter Saturation Voltage (Note 9)	VCE(sat)	_	_	1.5	V	Ic = 6A, I _B = 600mA
Base-Emitter Saturation Voltage (Note 9)	V _{BE(sat)}	_	_	1.4	V	I _C = 6A, I _B = 600mA
Base-Emitter Turn-On Voltage (Note 9)	V _{BE(on)}	_	_	2	V	Ic = 6A, VcE = 4V
DC Current Gain (Note 9)	h _{FE}	30	_	_		Vce = 4V, Ic = 0.3A
De Guitent Gain (Note 9)	TIFE	15	_	_		Vce = 4V, Ic = 3A
Small-Signal Current Gain	h _{fe}	20	_	_	_	$V_{CE} = 10V, I_{C} = 0.5A, f = 1kHz$
Current Gain-Bandwidth Product	f⊤	3		_	MHz	$V_{CE} = 10V, I_C = 0.5A, f = 100MHz$
Output Capacitance	Cobo		40	_	рF	V _{CB} = 10V, f = 1MHz
Input Capacitance	Cibo	_	960	_	рF	V _{EB} = 0.5V, f = 1MHz
Delay Time	t _d	_	50	_	ns	
Rise Time	tr	_	45	_	ns	Ic = 1A, Vcc = 10V,
Storage Time	ts	_	500	_	ns	$I_{B1} = -I_{B2} = 100 \text{mA}$
Fall Time	tf	_	65	_	ns	

Note:

9. Measured under pulsed conditions. Pulse width $\leq 300 \mu s.$ Duty cycle $\leq 2 \%.$



Typical Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)





Typical Electrical Characteristics ($@T_A = +25^{\circ}C$, unless otherwise specified.) (continued)

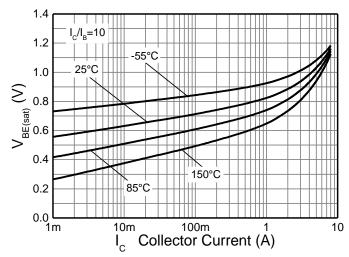


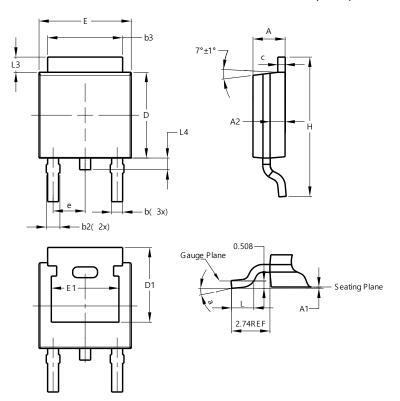
Figure 12. $V_{BE(sat)} V I_{C}$



Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

TO252 (DPAK)

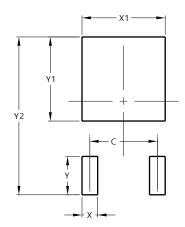


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TO252 (DPAK)					
Dim	Min	Max	Тур		
Α	2.19	2.39	2.29		
A1	0.00	0.13	0.08		
A2	0.97	1.17	1.07		
b	0.64	0.88	0.783		
b2	0.76	1.14	0.95		
b3	5.21	5.50	5.33		
С	0.45	0.58	0.531		
D	6.00	6.20	6.10		
D1	5.21				
е	2.286 BSC				
Е	6.45	6.70	6.58		
E1	4.32				
Н	9.40	10.41	9.91		
L	1.40	1.78	1.59		
L3	0.88	1.27	1.08		
L4	0.64	1.02	0.83		
а	0°	10°			
All Dimensions in mm					

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

TO252 (DPAK)



Dimensions	Value (in mm)
С	4.572
Х	1.060
X1	5.632
Υ	2.600
Y1	5.700
Y2	10 700



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